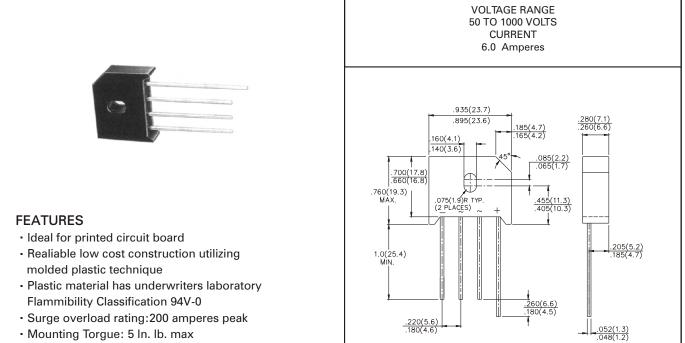
# **RS6 SERIES**

## SINGLE-PHASE SILICON BRIDGE





Dimensions in inches and (millimeters)

- UL recognized file # E149311
- Lead solderable per MIL-STD-202 mathod 208
- Electrically isolated base 1800Volts

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60 Hz. For capacitive load, derate current by 20%.

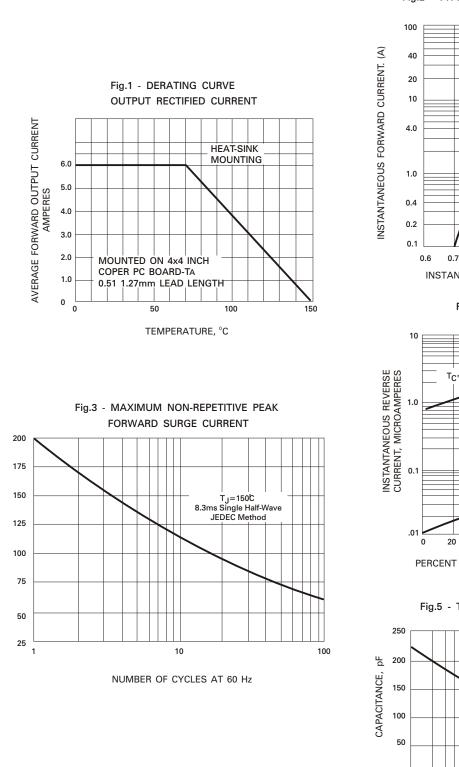
		RS6005	RS601	RS602	RS604	RS606	RS608	RS610	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	60	100	200	400	600	800	1000	V
Maximum Average Forward@ T_C=100°COutput Current@ T_A=65°C	V <sub>(AV)</sub>				6.0 6.0				A A
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	200							A
Maximum DC Forward Voltage drop per element at 3.0A DC	V <sub>F</sub>	1							V
Maximum DC Reverse Current at rated @ T <sub>A</sub> =25°C	I <sub>R</sub>				10				μA
DC Blocking Voltage Per Element @ T <sub>A</sub> =100°C					1				mA
Maximum Themal Resistance (Note 1)	RθJC				4.7				°C/W
Operating Temperature Range	Т <sub>Ј</sub>				-55 to +125	5			°C
Storage Temperature Range	T <sub>STG</sub>				-55 to +150	)			°C

## **RS6 SERIES**

## SINGLE-PHASE SILICON BRIDGE



RATING AND CHARACTERISTICS CURVES RS6 SERIES



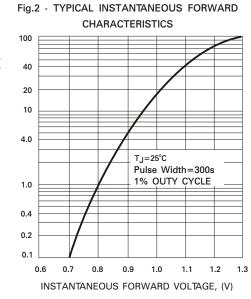
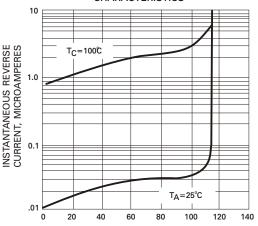


Fig.4 - TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE

Fig.5 - TYPICAL JUNCTION CAPACITANCE PER ELEMENT

